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Domain wall motion in perpendicular nanowires with surface roughness

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Overview

• Most micromagnetic simulations use idealised, smooth meshes. • In real-world systems, the production process introduces distortions on various scales (e.g., electron beam lithography, sputter deposition). • Distortions have a significant impact on magnetization dynamics. [1,2,3] • We present a systematic exploration of effects introduced by roughness. • We use finite element (FE)-based calculations with proper mesh distortion, in contrast to finite difference methods with varied material constants. [1,3]

Simulations with a smooth nanowire

The simulated system is a thin (multilayered) Co/Ni nanowire (800 nm x 20 nm x 5 nm) with strong perpendicular anisotropy ($K_1 = 3.8 \times 10^5 \text{ J/m}^3$). All computations were done using the FE-based simulation package nmag [4].

Phase 1: Relax system into stable configuration (perp. domain wall in center). *Phase 2*: Apply external field in vertical direction, record DW motion for 10 ns.



 \rightarrow Phase transition of DW motion from steady to oscillating at a critical field H_c ("Walker breakdown" [5]).





Simulations with a rough nanowire

(All simulations were performed with correlation length c = 2.0 nm.)







The magnetization angle inside the domain wall shows considerable jittering due to the interaction of the domain wall with the demagnetizing field caused by the edge roughness.

For weak fields the domain wall is pinned at the origin. Pinning can also occur when the domain wall is already in motion (as happens for $H_{ext} = 3 \times 10^3 \text{ A/m}$).

Notation: d = average distortion; α = Gilbert damping factor; h = strength (in 10³ A/m) of external field applied in z-direction.

Dependence of the domain wall velocity on the external field for various levels of roughness d. Note that pinning occurs for d>0 (and the depinning field increases with roughness). For weak fields the domain wall is slowed down considerably with increasing roughness, whereas for large fields this effect is reduced. Note that the Walker breakdown occurs *earlier* in rough wires (in contrast with results from [1]).

Summary

- Significant influence of roughness on domain wall dynamics.
- Domain wall gets pinned at the origin; can also get pinned during motion (even for stronger fields where pinning does not occur for weaker fields).
- Slowdown of the domain wall with increasing roughness
- (effect is more prominent for weak fields)
- Walker breakdown already occurs for weaker fields in rough wires.

References

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